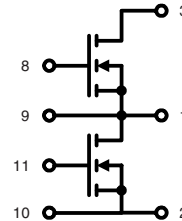


# Dual Trench MOSFET Module

Phaseleg Configuration

Preliminary data



$$V_{DSS} = 100 \text{ V}$$

$$I_{D25} = 1000 \text{ A}$$

$$R_{DS(on)} = 0.75 \text{ m}\Omega$$

MOSFET T1 + T2			Maximum Ratings	
Symbol	Conditions			
$V_{DSS}$	$T_{VJ} = 25^\circ\text{C to } 150^\circ\text{C}$		100	V
$V_{GS}$			$\pm 20$	V
$I_{D25}$	$T_C = 25^\circ\text{C}$	①	1000	A
$I_{D80}$	$T_C = 80^\circ\text{C}$	①	800	A
$I_{F25}$	(diode) $T_C = 25^\circ\text{C}$	①	1000	A
$I_{F80}$	(diode) $T_C = 80^\circ\text{C}$	①	800	A

### Features

- Trench MOSFETs
  - low  $R_{DS(on)}$
  - optimized intrinsic reverse diode
- package
  - low inductive current path
  - screw connection to high current main terminals
  - use of non interchangeable connectors for auxiliary terminals possible
  - Kelvin source terminals for easy drive
  - isolated DCB ceramic base plate

Symbol	Conditions	Characteristic Values ( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$R_{DS(on)}$	$V_{GS} = 10 \text{ V}; I_D = I_{D80}$		0.75	1.2 m $\Omega$
$V_{GS(th)}$	$V_{DS} = 20 \text{ V}; I_D = 10 \text{ mA}$	2		4 V
$I_{DSS}$	$V_{DS} = V_{DSS}; V_{GS} = 0 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.5	0.15 mA mA
$I_{GSS}$	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0 \text{ V}$			1.5 $\mu\text{A}$
$Q_g$ $Q_{gs}$ $Q_{gd}$	$V_{GS} = 10 \text{ V}; V_{DS} = 80 \text{ V}; I_D = 1000 \text{ A}$		2355	nC
			495	nC
			1000	nC
$t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$	$V_{GS} = 10 \text{ V}; V_{DS} = 50 \text{ V};$ $I_D = 250 \text{ A}; R_G = 0.68 \Omega$		50	ns
			100	ns
			260	ns
			100	ns
$V_F$	(diode) $I_F = 500 \text{ A}; V_{GS} = 0 \text{ V}$		1.0	1.5 V
$t_{rr}$	(diode) $I_F = 200 \text{ A}; -di/dt = 1000 \text{ A}/\mu\text{s}; V_{DS} = 30 \text{ V}$		100	ns
$R_{th(jc)}$ $R_{th(js)}$	with heat transfer paste		0.12	0.06 K/W K/W

① additional current limitation by external leads

IXYS reserves the right to change limits, test conditions and dimensions.

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### Applications

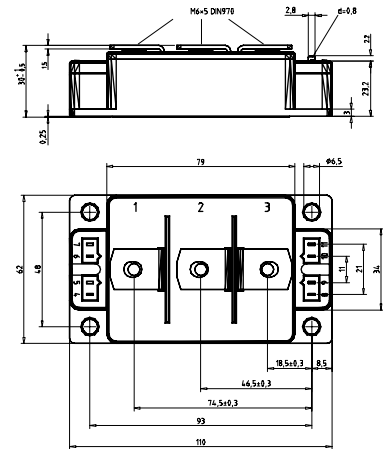
- converters with high power density for
  - main and auxiliary AC drives of electric vehicles
  - 4 quadrant DC drives
- power supplies with low input voltage, e.g. from fuel cells or solar cells

### Module

Symbol	Conditions	Maximum Ratings	
$I_{RMS}$	per main terminal	500	A
$T_{VJ}$		-40...+175	°C
$T_{stg}$		-40...+125	°C
$V_{ISOL}$	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$	3600	V~
$M_d$	Mounting torque (M6)	2.25 - 2.75	Nm
	Terminal connection torque (M6)	4.5 - 5.5	Nm

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
Weight			250	g

Dimensions in mm (1 mm = 0.0394")



### Optional accessories for modules

keyed twin plugs  
(UL758, style 1385, CSA class 5851,  
guide 460-1-1)

- Type ZY180L with wire length 350mm
  - for pins 4 (yellow wire) and 5 (red wire)
  - for pins 11 (yellow wire) and 10 (red wire)
- Type ZY180R with wire length 350mm
  - for pins 7 (yellow wire) and 6 (red wire)
  - for pins 8 (yellow wire) and 9 (red wire)